

RS2A - RS2M



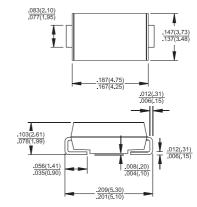
2.0 AMPS. Surface Mount Fast Recovery Rectifiers

SMB/DO-214AA



Features

- For surface mounted application
- Glass passivated junction chip
- Built-in strain relief, ideal for automated placement
- Plastic material used carries Underwriters Laboratory Classification 94V-0
- Fast switching for high efficiency
- High temperature soldering: 260 °C / 10 seconds at terminals
- Green compound with suffix "G" on packing code & prefix "G" on datecode.



Dimensions in inches and (millimeters)

Marking Diagram



RS2X = Specific Device Code = Green Compound G

= Year

= Work Month

Mechanical Data

Cases: Molded plastic

Terminals: Pure tin plated, Lead free.

Polarity: Indicated by cathode band

Packing: 12mm tape per EIA STD RS-481

Weight: 0.093 gram

Maximum Ratings and Electrical Characteristics

Rating at 25 °C ambient temperature unless otherwise specified. Single phase, half wave, 60 Hz, resistive or inductive load. For capacitive load, derate current by 20%

Type Number	Symbol	RS 2A	RS 2B	RS 2D	RS 2G	RS 2J	RS 2K	RS 2M	Units
Maximum Recurrent Peak Reverse Voltage	VRRM	50	100	200	400	600	800	1000	V
Maximum RMS Voltage	VRMS	35	70	140	280	420	560	700	V
Maximum DC Blocking Voltage	VDC	50	100	200	400	600	800	1000	V
Maximum Average Forward Rectified Current See Fig. 1 @T _L =100°C	I (AV)	2.0							А
Peak Forward Surge Current, 8.3 ms Single Half Sine-wave Superimposed on Rated Load (JEDEC method)	I FSM	50							А
Maximum Instantaneous Forward Voltage @ 2.0A	VF	1.3							V
Maximum DC Reverse Current		5							uA
\bigcirc T _A =25 °C at Rated DC Blocking Voltage \bigcirc T _A =125 °C	I R	200							uA
Maximum Reverse Recovery Time (Note 1)	Trr		150 250 500				nS		
Typical Junction Capacitance (Note 2)	Cj	50							pF
Typical Thermal Resistance (Note 3)	RθJA	55 18							°C /W
	RθJL								
Operating Temperature Range	Тл	-55 to +150							°C
Storage Temperature Range	Тѕтс	-55 to +150							°C

Notes: 1. Reverse Recovery Test Conditions: I_F=0.5A, I_R=1.0A, I_{RR}=0.25A

2. Measured at 1 MHz and Applied V_R=4.0 Volts

3. Thermal Resistance from Junction to Ambient and Junction to Lead Mounted on P.C.B. with 0.4" x 0.4" (10mm x 10 mm) Copper Pad Areas.

Version: B08



RATINGS AND CHARACTERISTIC CURVES (RS2A THRU RS2M)

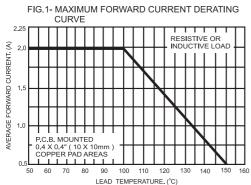


FIG.3- MAXIMUM NON-REPETITIVE PEAK FORWARD

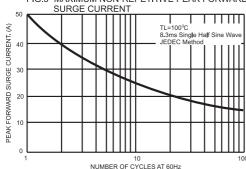


FIG.4-TYPICAL JUNCTION CAPACITANCE

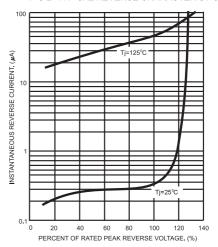
90

(d)
TypeSiC
Tet.0MHz
Valge50mVp-p

50

REVERSE VOLTAGE. (V)

FIG.2- TYPICAL REVERSE CHARACTERISTICS



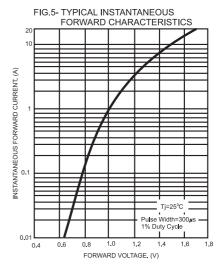
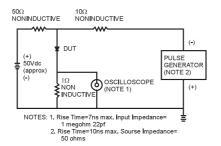
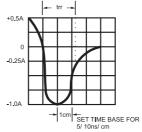


FIG.6- REVERSE RECOVERY TIME CHARACTERISTIC AND TEST CIRCUIT DIAGRAM





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